

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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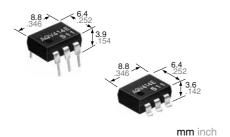




c**TL**

Normally closed 6-pin type of 400V load voltage

PhotoMOS® GU 1 Form B (AQV414)



RoHS compliant

FEATURES

1. Low on-resistance (typ. 26 Ω) for normally-closed type

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

Cross section of the normally-closed type of power MOS

Passivation membrane
Source electrode Gate electrode insulating membrane
Gate oxidation membrane

2. Controls low-level analog signals
PhotoMOS feature extremely low closedcircuit offset voltage to enable control of
low-level analog signals without
distortion.

3. High sensitivity and low onresistance

Can control max. 0.15 A load current with 5 mA input current.

4. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Security equipment
- Telephone equipment (Dial pulse)
- Measuring instruments

TYPES

	I/O isolation voltage	Output rating*		Dogleoge		Par	Packing quantity			
					Through hole terminal Su				rface-mount terminal	
		E Load Load voltage current	Lood	Package		Tape and reel pa		l packing style		
				Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel	
AC/DC dual use	1,500 V AC	400 V	120 mA	DIP6-pin	AQV414	AQV414A	AQV414AX	AQV414AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

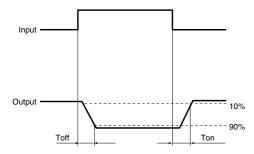
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Symbol	Type of connection	AQV414(A)	Remarks	
Input	LED forward current	lF		50 mA	
	LED reverse voltage	VR		5 V	
	Peak forwrd current	I FP		1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin		75 mW	
	Load voltage (peak AC)	VL		400 V	
			Α	0.12 A	
Outnot	Continuous load current	l _L	В	0.13 A	A connection: Peak AC, DC B, C connection: DC
Output			С	0.15 A	B, O dofinedion. Bo
	Peak load current	Ipeak		0.3 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	Pout	1 \ [500 mW	
Total power dissipation		P⊤		550 mW	
I/O isolation voltage		Viso		1,500 V AC	
Temperature limits	Operating	Topr		-40°C to +85°C −40°F to +185°F	Non-condensing at low temperatures
	Storage	Tstg	1	-40°C to +100°C -40°F to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

		Symbol	Type of connection	AQV414(A)	Condition	
	LED operate (OFF)	Typical	Foff	_	1.0 mA	IL = Max.
	current	Maximum			3.0 mA	
Input	LED reverse (ON) current	Minimum	IFon	_	0.4 mA	IL = Max.
Input	LED reverse (ON) current	Typical			0.95 mA	
	LED drapaut voltage	Typical	VF	_	1.25 V (1.14 V at I _F = 5 mA)	I _F = 50 mA
	LED dropout voltage	Maximum			1.5 V	
		Typical	Ron	А	26 Ω	I _F = 0 mA I _L = Max. Within 1 s on time
		Maximum			50 Ω	
		Typical	Ron	В	20 Ω	I _F = 0 mA I _L = Max. Within 1 s on time
Output	On resistance	Maximum			25 Ω	
·		Typical	Ron	С	10 Ω	I _F = 0 mA
		Maximum			12.5 Ω	I∟ = Max. Within 1 s on time
	Off state leakage current	Maximum	ILeak	_	1 μΑ	$I_F = 5 \text{ mA}$ $V_L = \text{Max}$.
	Operate (OFF) time*	Typical	off	_	0.47 ms	I _F = 0 mA → 5 mA I _L = 120 mA
		Maximum			1.0 ms	
	D (ON) :: +	Typical	Ton	_	0.28 ms	I _F = 5 mA → 0 mA I _L = 120 mA
Transfer characteristics	Reverse (ON) time*	Maximum			1.0 ms	
onaraotoristics	I/O sonositores	Typical	Ciso	_	0.8 pF	f = 1 MHz
	I/O capacitance	Maximum			1.5 pF	V _B = 0 V
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 MΩ	500 V DC

^{*}Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

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Item	Symbol	Recommended value	Unit		
Input LED current	lF	5	mA		

■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

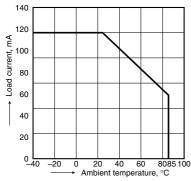
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REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

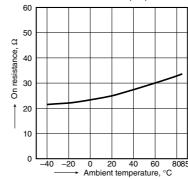
Type of connection: A



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 0 mA;

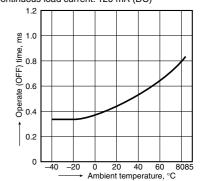
Continuous load current: 120 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

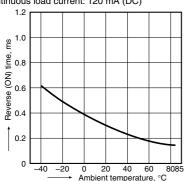
LED current: 5mA; Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC)



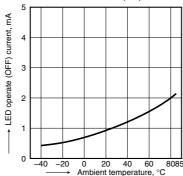
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



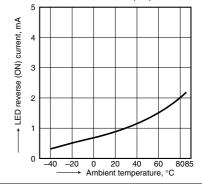
5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC)

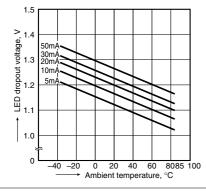


6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: 400 V (DC);

Continuous load current: 120 mA (DC)

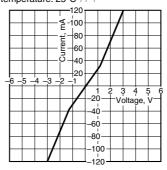


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



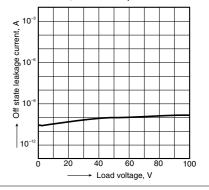
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



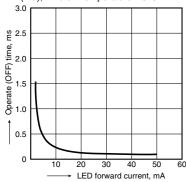
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Ambient temperature: 25°C 77°F



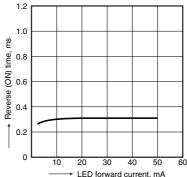
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Frequency: 1 MHz; Ambient temperature: 25° C 77° F

